

### Integrated, scalable spectral sensors

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Where innovation starts

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### **Our dream**

### Replace this:



### With this:



#### Microspectrometer

- Bulky
- Expensive (1'000-10'000 EUR)
- High-performance
- General purpose
- Single-pixel

- Integrated
- Cheap (10-100 EUR)
- High-performance
- Dedicated to specific application
- Arrays



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### How to integrate a spectrometer



the linewidth)

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#### Key functionalities:

- 1) Filtering
- 2) Actuation
- 3) Detection

### Filtering with photonic crystal cavities



- Very high Q factor possible (up to 10<sup>6</sup>)
- Small Volume ~  $\lambda^3 \rightarrow$  Large free spectral range possible
- Light mass (~ 10 picograms) → high speed



### **Cavity actuation**

Double-membrane structures: Change *effective index* 



### **Electrostatic actuation:**





### **Nanomechanical cavities**



# Experimental tuning range: 20-30 nm



### Integrated microspectrometer



### **Microspectrometers: Results**



Present devices offer high resolution (100 pm) but low spectral range (20 nm)

Our next goal: Microspectrometer with 0.5-1 nm resolution, 200 nm spectral range in the 1500-2000 nm region

Applications:

- Mobile healthcare (monitoring of glucose, triglycerides, ...)
- Gas sensing
- etc

Notes:

- Light source and spectrometer can be integrated and fitted in a smartphone
- Imaging arrays can be fabricated
- Concept can be extended to other types of optical detectors



### **PSN: Nano-opto-electro-mechanical systems**

### Electromechanically-tuneable photonic crystal cavity:



## **NOEMS:** Application as microspectrometers

HF absorption line (16 pm):



- Can measure emission or absorption lines
- Resolution down to 100 fm/(Hz)<sup>0.5</sup>

• Fully-integrated, mass-manufacturable

Patent filed

#### Double-membrane photonic crystal

- Modes hybridize and form supermodes
- Changing separation tunes the supermodes
- Electrostatic actuation via p-i-n junction



### 23 nm tuning of monopole mode in H0 cavity:



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### 3) Detection



### **Concept: Detector + Tuneable Filter**





### **Fabricated structure**





### **Sensing: Modes of operation**

#### Spectrometer action (tuneable filter):

- Changing Voltage changes  $\boldsymbol{\lambda}$
- Incoming light read as photocurrent



- **Displacement** transduced as a small change in photocurrent







### μ-spectrometer demonstration



- Resolution ~ 150 pm
- Responsivity changes due to changing field overlap with QDs

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### **Demonstration of background suppression**



Additional advantage: Higher wavelength resolution on a single line

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 $d\lambda$ 

### Application of microspectrometer in gas sensing





- P(3) line: 1312.591 nm
- 16 pm linewidth, 6 dB depth (at 50 Torr pressure)
- Use of resonance modulation scheme is crucial!



1318 nm

### **Gas sensing: Measurements**

Excitation: SLED + HF cell + filter (1310 nm)

Detection: cavity mode sweeping



HF absorption line P(3) @ 1312.59 nm detected



### **Displacement sensor demonstration**

### **Measuring thermal motion:**





Estimated amplitude of thermal motion:

 $z_{RMS} \approx 20 \ pm \ (@RT)$ 



### **Displacement sensor demonstration**



✓ µ-spectrometer with resolution down to 80 pm over a range of up to 23 nm

- Resonance modulation scheme with high rejection ratio (30dB) and resolution (<1 pm when used as a wavemeter)</li>
- ✓ Application as gas sensor (HF detection)
- ✓ Fully integrated optomechanical displacement sensor

All this in an integrated device, few tens of  $\mu$ m in size, suitable for mass production

### **Questions?**



### **Tuning: pull-in limitation**

#### Tuning is limited by pull-in effect to 2/3 of nominal distance



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#### (Li) (1600 (Li) (

Simulation: Tuning from d = 240nm to 160nm provides:  $\Delta \lambda = 28 \text{ nm}$ 

#### Pull-in effect is not reversible



Experimental: 
$$\langle x^2 \rangle_{th} = \int S_{xx} df = (6.3 \ pm)^2$$

Model:  $k_B T / m_{eff} \Omega_M^2 = (22 \ pm)^2$ 

- Transduction currently limited
- by diode speed ( $f_{cut-off} < f_1$ )
- To be addressed: Non-ohmic contacts

**Displacement PSD:** 

$$S_{xx}(f) = \frac{P_{out}(f)}{Z A g_{OM}^2 \left(\frac{\partial I}{\partial \omega}\right)^2}$$

$$g_{OM} = \frac{\partial \omega}{\partial x} = 2 \cdot 10^{20} \ s^{-1}/m$$



### Mode distribution in an asymmetric system



### Surface under the curve vs. laser power





### **Pull-in**

#### Tuning is limited by pull-in effect to 2/3 of nominal distance



Electrostatic









Simulation: Tuning from d = 240nm to 160nm provides:  $\Delta \lambda$  =28 nm



- > Tuning range ( $\Delta\lambda$ ) > 50 nm
- Resolution ( $\delta\lambda$ ) < 100 pm
- Free spectral range (FSR) > 50 nm
- $\blacktriangleright$  Responsivity = 0.05 A/W
- Rejection ration > 15 dB

- $\rightarrow$  (7nm extended to 25 nm)
- $\rightarrow$  (76 pm)
- $\rightarrow$  (up to 30 nm for H0 cavity)
- $\rightarrow$  (up to 0.02 A/W)
- $\rightarrow$  (30 dB)













### **Fabrication of full devices:**

Double membrane device with an 10µm L3 modified cavity	n

Double membrane device with highlighted contact pads

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- Over 50 fabrication steps:
- Multiple wet and dry etching steps
- 3 Optical lithography steps (for defining contact pad positions)
- Metal evaporation
- Electron beam lithography (for patterning the photonic crystal)

